



**THE DATASHEET OF  
ZXMP6A16DN8TA**



## Product Summary

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	Package	I <sub>D</sub> T <sub>A</sub> = +25°C (Notes 4 & 6)
-60V	85mΩ @ V <sub>GS</sub> = -10V	SO-8	-3.9A
	125mΩ @ V <sub>GS</sub> = -4.5V		-3.2A

## Description

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

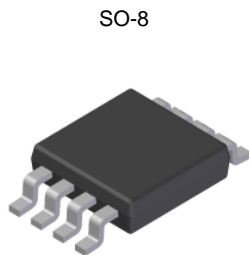
- DC-DC Converters
- Power Management Functions
- Disconnect Switches
- Motor Control

## Features

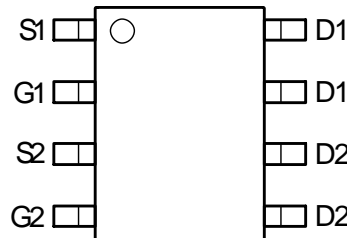
- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- Low Profile SOIC Package
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **An Automotive-Compliant Part is Available Under Separate Datasheet ([ZXMP6A16DN8Q](#))**

## Mechanical Data

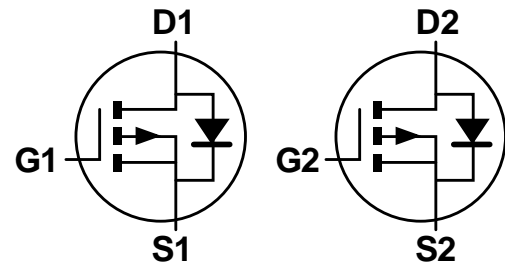
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.074 grams (Approximate)



Top View



Top View



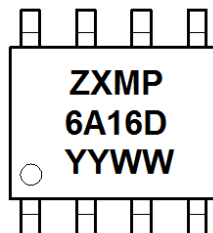
Equivalent Circuit

## Ordering Information (Note 4)

Part Number	Case	Packaging
ZXMP6A16DN8TA	SO-8	500/Tape & Reel
ZXMP6A16DN8TC	SO-8	2,500/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



ZXMP6A16D = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Year (ex: 16 = 2016)  
 WW = Week (01 - 53)

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

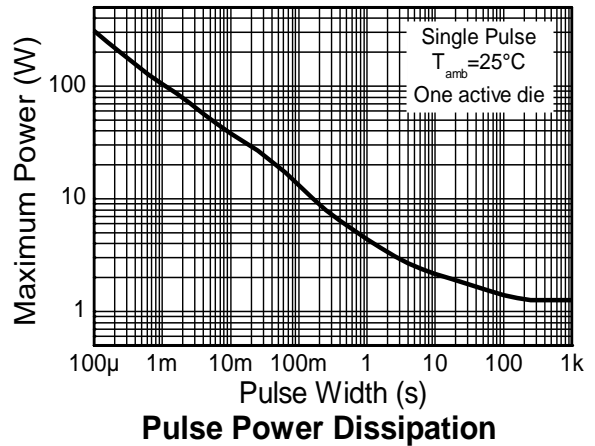
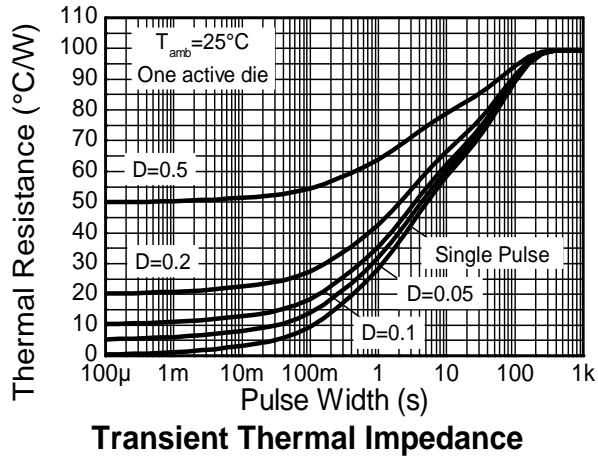
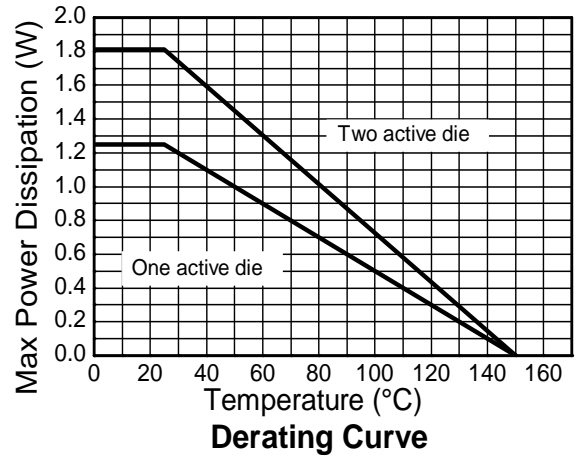
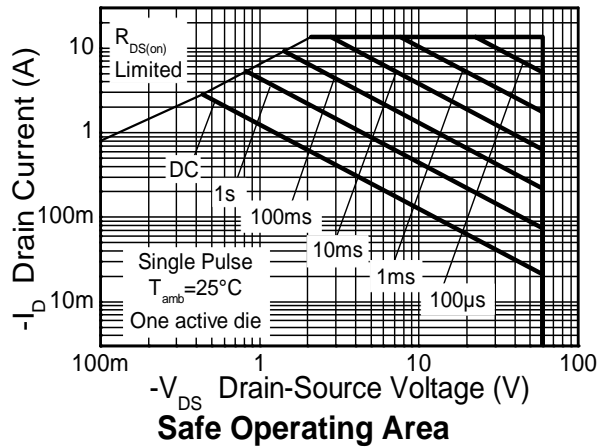
Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	-60	V
Gate-Source Voltage		V <sub>GS</sub>	±20	V
Continuous Drain Current	V <sub>GS</sub> = 10V	(Note 5)	-3.9	A
		(Notes 7 & 9)	-3.1	
		T <sub>A</sub> = +70°C (Notes 7 & 9)	-2.9	
		(Notes 6 & 9)		
Pulsed Drain Current		I <sub>DM</sub>	-18.3	A
Continuous Source Current (Body Diode)		I <sub>S</sub>	-3.2	A
Pulsed Source Current (Body Diode)		I <sub>SM</sub>	-18.3	A

**Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Notes 6 & 9)	P <sub>D</sub>	1.25	W mW/°C
			10.0	
	(Notes 6 & 10)		1.81	
			14.5	
Thermal Resistance, Junction to Ambient	(Notes 7 & 9)	R <sub>θJA</sub>	2.15	°C/W
	(Notes 6 & 9)		17	
	(Notes 6 & 10)		100	
Thermal Resistance, Junction to Lead	(Notes 7 & 9)	R <sub>θJL</sub>	70	°C/W
	(Notes 9 & 11)		60	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
5. AEC-Q101 V<sub>GS</sub> maximum is ±16V.
  6. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  7. Same as Note (5), except the device is measured at t ≤ 10 sec.
  8. Same as Note (5), except the device is pulsed with D = 0.02 and pulse width 300µs.
  9. For a dual device with one active die.
  10. For a device with two active die running at equal power.
  11. Thermal resistance from junction to solder-point.

**Thermal Characteristics** (Continued)

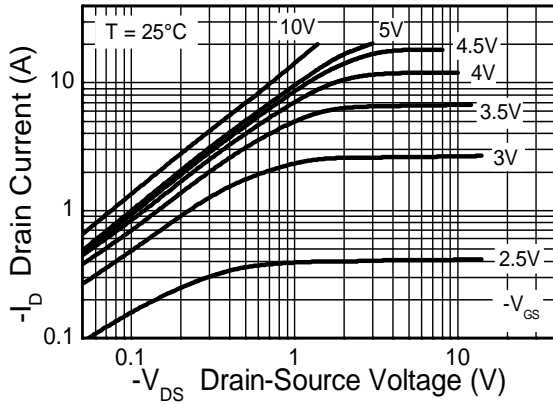


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

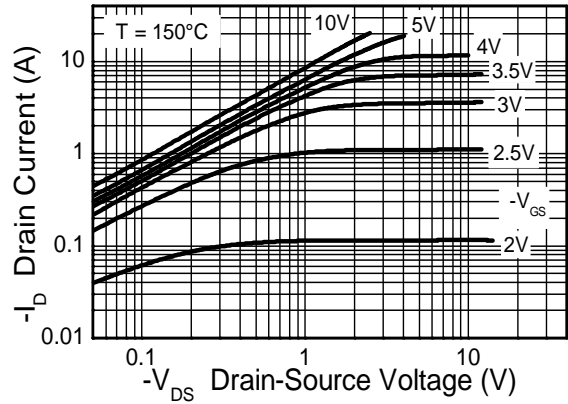
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
<b>OFF CHARACTERISTICS</b>							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-60	—	—	V	I <sub>D</sub> = -250μA, V <sub>GS</sub> = 0V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	-1.0	μA	V <sub>DS</sub> = -60V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	
<b>ON CHARACTERISTICS</b>							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.0	—	—	V	I <sub>D</sub> = -250μA, V <sub>DS</sub> = V <sub>GS</sub>	
Static Drain-Source On-Resistance (Note 12)	R <sub>DS(ON)</sub>	—	—	85	mΩ	V <sub>GS</sub> = -10V, I <sub>D</sub> = -2.9A	
			—	125		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -2.4A	
Forward Transconductance (Notes 12 & 13)	g <sub>FS</sub>	—	7.2	—	S	V <sub>DS</sub> = -15V, I <sub>D</sub> = -2.9A	
Diode Forward Voltage (Note 12)	V <sub>SD</sub>	—	-0.85	-0.95	V	I <sub>S</sub> = -3.4A, V <sub>GS</sub> = 0V, T <sub>J</sub> = +25°C	
Reverse Recovery Time (Note 13)	t <sub>RR</sub>	—	29.2	—	ns	I <sub>S</sub> = -2A, di/dt = 100A/μs,	
Reverse Recovery Charge (Note 13)	Q <sub>RR</sub>	—	39.6	—	nC	T <sub>J</sub> = +25°C	
<b>DYNAMIC CHARACTERISTICS (Note 14)</b>							
Input Capacitance	C <sub>ISS</sub>	—	1,021	—	pF	V <sub>DS</sub> = -30V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	C <sub>OSS</sub>	—	83.1	—	pF		
Reverse Transfer Capacitance	C <sub>RSS</sub>	—	56.4	—	pF		
Total Gate Charge	Q <sub>G</sub>	—	12.1	—	nC	V <sub>GS</sub> = -5V	V <sub>DS</sub> = -30V, I <sub>D</sub> = -2.9A
Total Gate Charge	Q <sub>G</sub>	—	24.2	—	nC	V <sub>GS</sub> = -10V	
Gate-Source Charge	Q <sub>GS</sub>	—	2.5	—	nC		
Gate-Drain Charge	Q <sub>GD</sub>	—	3.7	—	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	—	3.5	—	ns	V <sub>DD</sub> = -30V, V <sub>GS</sub> = -10V, I <sub>D</sub> = -1A, R <sub>G</sub> ≅ 6.0Ω	
Turn-On Rise Time	t <sub>R</sub>	—	4.1	—	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	35	—	ns		
Turn-Off Fall Time	t <sub>F</sub>	—	10	—	ns		

- Notes:
12. Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%
  13. For design aid only, not subject to production testing.
  14. Switching characteristics are independent of operating junction temperatures.

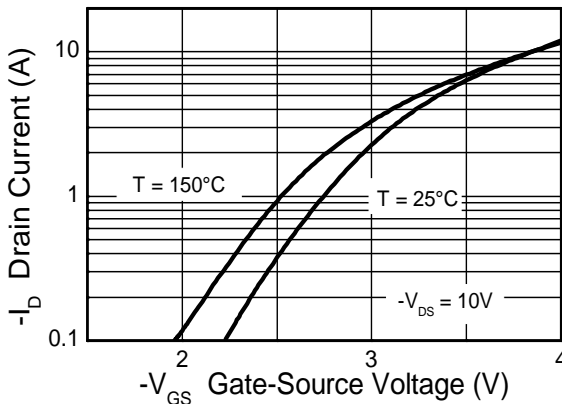
**Typical Characteristics**



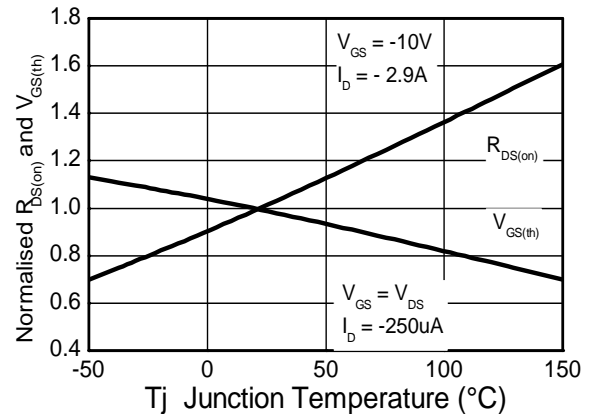
**Output Characteristics**



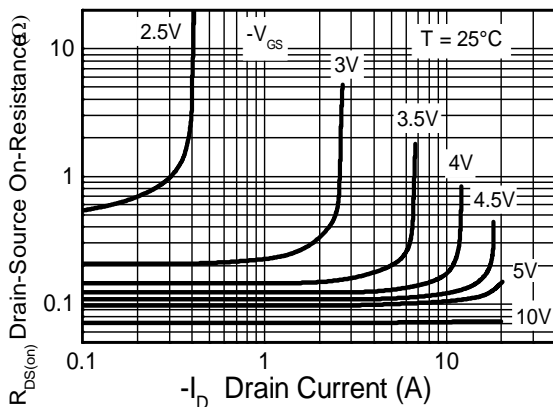
**Output Characteristics**



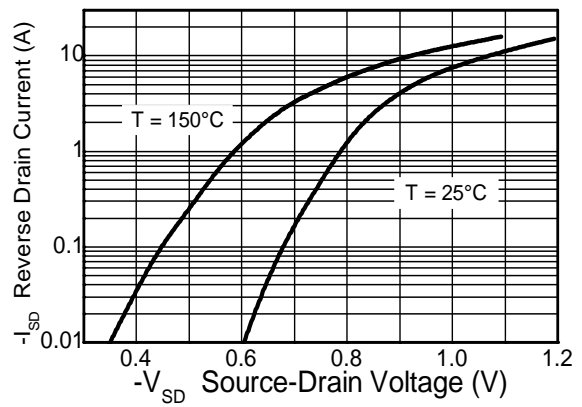
**Typical Transfer Characteristics**



**Normalised Curves v Temperature**

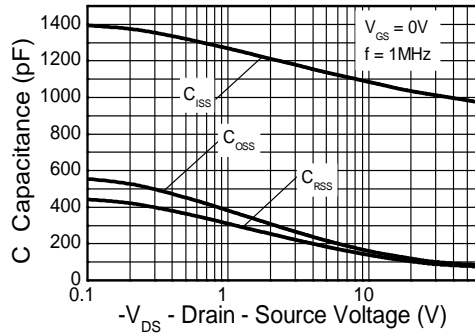


**On-Resistance v Drain Current**

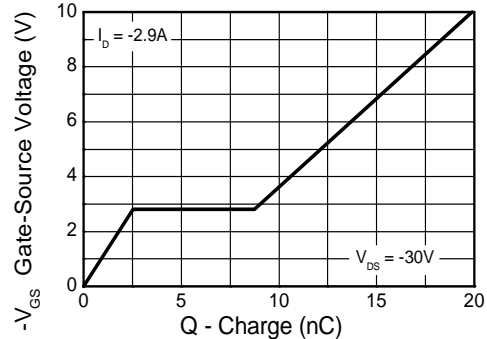


**Source-Drain Diode Forward Voltage**

**Typical Characteristics** (Continued)

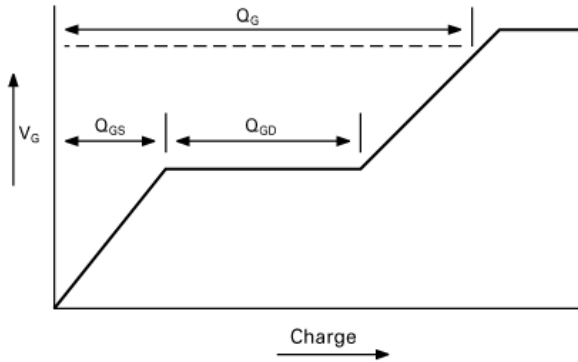


**Capacitance v Drain-Source Voltage**

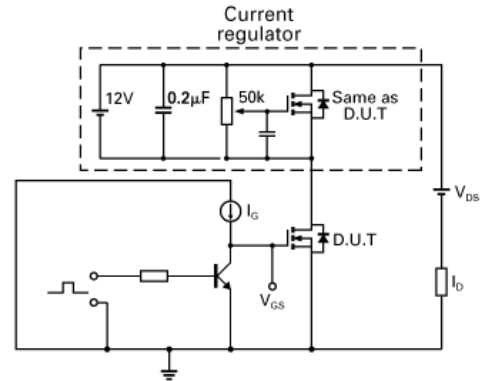


**Gate-Source Voltage v Gate Charge**

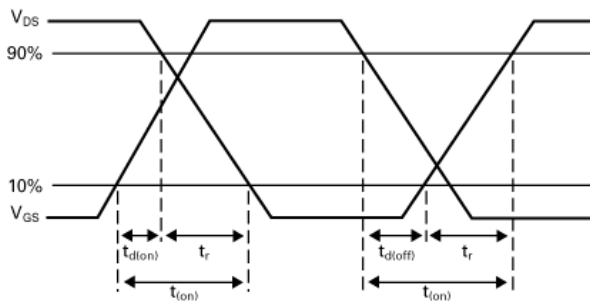
**Test Circuits**



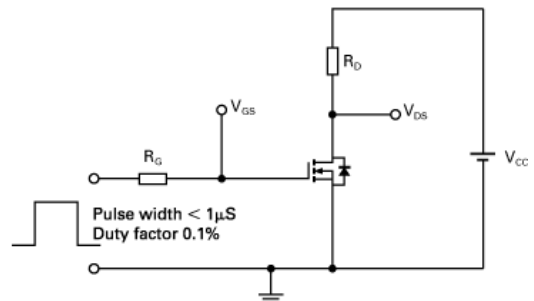
**Basic gate charge waveform**



**Gate charge test circuit**



**Switching time waveforms**

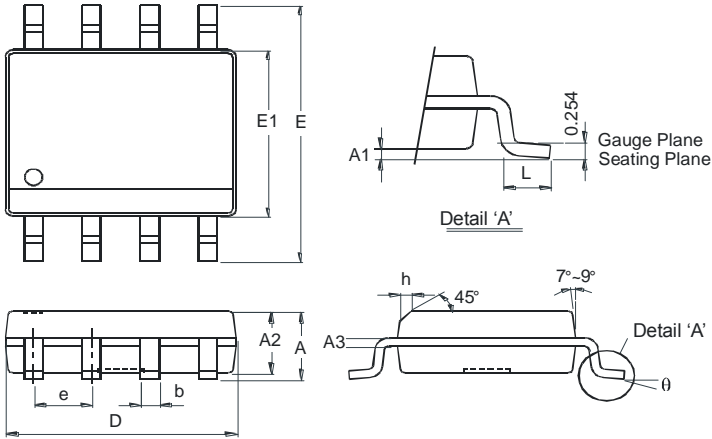


**Switching time test circuit**

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SO-8

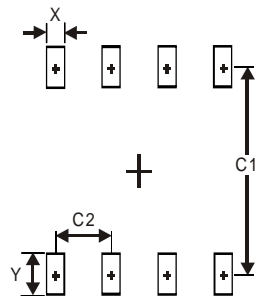


SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°
<b>All Dimensions in mm</b>		

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SO-8



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

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